TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSVII)

TK6A50D

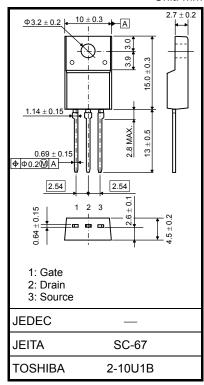
Switching Regulator Applications

- Low drain-source ON-resistance: $R_{DS(ON)} = 1.2 \Omega$ (typ.)
- High forward transfer admittance: $|Y_{fS}| = 2.5 \text{ S}$ (typ.)

Absolute Maximum Ratings (Ta = 25°C)

- Low leakage current: I_{DSS} = 10 μ A (max) (V_{DS} = 500 V)
- Enhancement mode: V_{th} = 2.4 to 4.4 V (V_{DS} = 10 V, I_D = 1 mA)

Characteristics Symbol Rating Unit Drain-source voltage 500 ٧ VDSS v ±30 Gate-source voltage V_{GSS} 6 DC (Note 1) I_D Drain current А Pulse (t = 1 ms) 24 IDP (Note 1) Drain power dissipation ($Tc = 25^{\circ}C$) W P_D 35 Single pulse avalanche energy EAS 144 mJ (Note 2) Avalanche current 6 IAR А 3.5 Repetitive avalanche energy (Note 3) EAR mJ °C Channel temperature T_{ch} 150 °C Storage temperature range Tstg -55 to 150



Weight: 1.7 g (typ.)

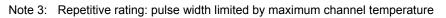
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

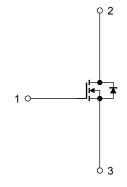
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	3.57	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 90 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}$ (initial), L = 6.8 mH, R_G = 25 Ω , I_{AR} = 6 A



This transistor is an electrostatic-sensitive device. Handle with care.



Start of commercial production 2009-04

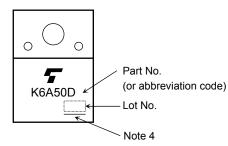
Electrical Characteristics (Ta = 25°C)

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 30~V,~V_{DS}=0~V$	_		±1	μA
Drain cut-off current		I _{DSS}	$V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_		10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	500	_		V
Gate threshold voltage		V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.4	_	4.4	V
Drain-source ON resistance		R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}$		1.2	1.4	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}$	0.6	2.5	_	S
Input capacitance		C _{iss}			540		
Reverse transfer capacitance		C _{rss}	V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz	_	3	_	pF
Output capacitance		C _{oss}			60		
Switching time	Rise time	tr	$\begin{array}{c} 10 \text{ V} \\ \text{V}_{GS} \\ 0 \text{ V} \\ 50 \Omega \end{array} \begin{array}{c} \text{I}_{D} = 3 \text{ A} \\ \text{V}_{OUT} \\ \text{V}_{DD} \approx 200 \text{ V} \\ \text{V}_{DD} \approx 200 \text{ V} \\ \text{Duty} \leq 1\%, t_{W} = 10 \ \mu\text{s} \end{array}$	_	18		
	Turn-on time	t _{on}			40		
	Fall time	t _f		_	8		ns
	Turn-off time	t _{off}			55	_	
Total gate charge		Qg		_	11		
Gate-source charge		Q _{gs}	$V_{DD}\approx 400~V,~V_{GS}=10~V,~I_{D}=6~A$		6		nC
Gate-drain charge		Q _{gd}		—	5		

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	6	А
Pulse drain reverse current (Note 1)	I _{DRP}	—	_	_	24	А
Forward voltage (diode)	V _{DSF}	I _{DR} = 6 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 6 \text{ A}, V_{GS} = 0 \text{ V},$		1000	_	ns
Reverse recovery charge	Q _{rr}	dl _{DR} /dt = 100 A/μs	_	6	_	μC

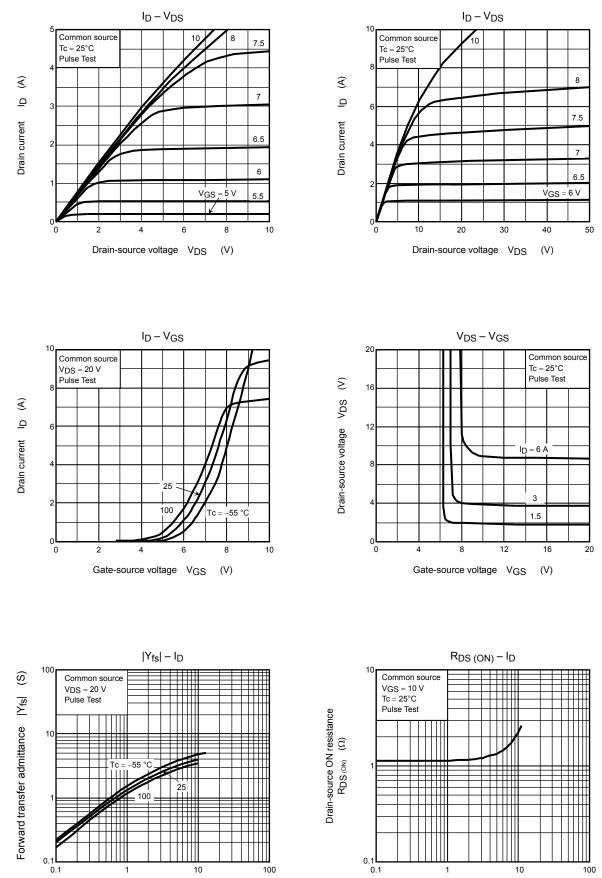
Marking



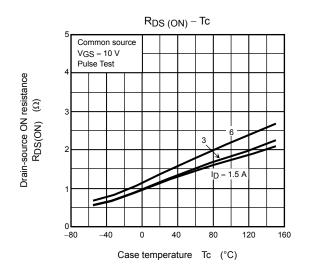
Note 4: A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

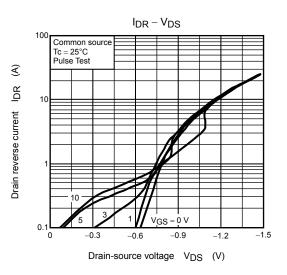
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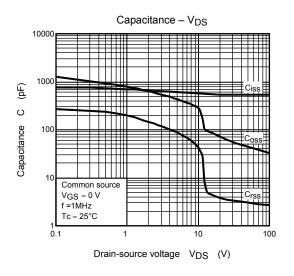
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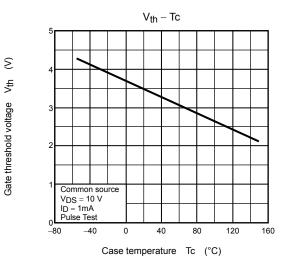


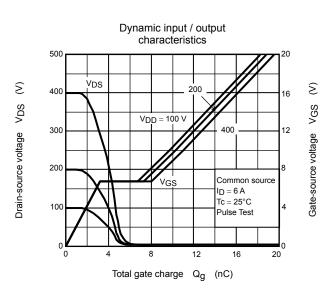
Drain current ID (A)

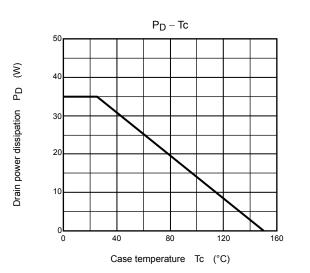


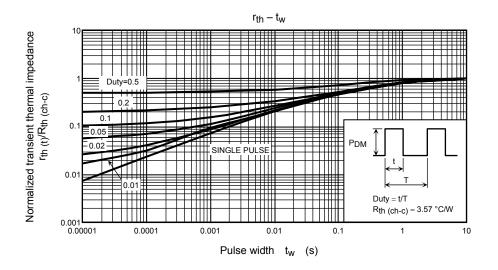


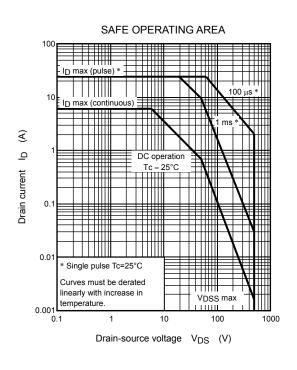


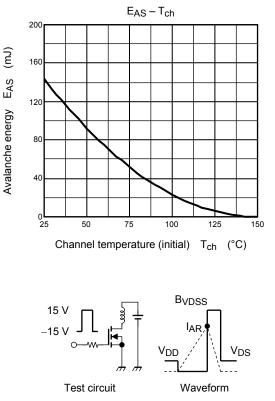












RG = 25 Ω	$EAS = \frac{1}{2} \cdot L \cdot l^2 \cdot ($	BVDSS
V _{DD} = 90 V, L = 6.8 mH		BVDSS-VDD

<u>TOSHIBA</u>

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